Reflection and transmission in nonlocal susceptibility models with multiple resonances

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We consider a semi-infinite dielectric with multiple spatially dispersive resonances in the susceptibility. The effect of the boundary is described by an arbitrary reflection coefficient for polarization waves in the material at the surface, with specific values corresponding to various additional boundary conditions (ABCs) for Maxwell's equations. We derive exact expressions for the electromagnetic reflection and transmission coefficients and present the results for a variety of materials with multiple exciton bands. We find an improved single-band approximation for heavy/light exciton bands and extend our model to exciton dispersion relations with linear *k* terms which occur in uniaxial crystals. Finally, we calculate the spectral energy density of thermal and zero-point radiation for a variety of multiresonance models and ABCs.

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I. INTRODUCTION

The susceptibility describing the material response to an applied electromagnetic field contains both temporal and spatial dispersion [1,2]. As a result of the latter, the induced polarization at any point in the medium depends on the applied field in the region surrounding that point. This behavior can be due to a range of excitations within the material, such as phonons or excitons, each with their own associated resonance in the susceptibility. While this nonlocal response is often negligible in comparison to the frequency dependence, there are cases where it can play a significant role, such as metallic nanostructures [3–7], radiative heat transfer [8,9], spontaneous emission [10–14], spectral energy density [15], and Casimir self-forces [10]. Spatial dispersion is also important in semiconductors, where the complex electronic band structure can lead to many excitations [16], each with their own nonlocal response. In this paper, we continue our previous work on nonlocal response [15] by extending results on reflection and transmission at planar boundaries to the case where the medium has multiple spatially dispersive resonances.

The susceptibility is typically expressed as a sum of resonances. Nonlocal response is included as a *k* dependence in the model parameters, but is usually limited to a *k*-dependent resonant frequency. Hopfield and Thomas [17] proposed the following model, based on the properties of semiconductors, but it can also be derived from a simple classical model [18]:

$$\chi(\mathbf{k},\omega) = \chi_0 + \sum_{m=1}^{M} \frac{\omega_{pm}^2}{\omega_{Tm}^2(k) - \omega^2 - i\gamma_m\omega},$$
 (1)

where $\omega_T(k)$ is the resonant frequency, γ quantifies the absorption, and ω_p is the oscillator strength. The term χ_0 collects contributions from other resonances and acts as a background susceptibility. For the sake of simplicity, the parabolic dispersion

$$\hbar\omega_T(k) = \hbar\omega_T + \frac{\hbar^2 k^2}{2m_{\text{ex}}}, \quad \omega_T^2(k) \approx \omega_T^2 + Dk^2$$
 (2)

was used [17] to describe the exciton bands in the medium, where $m_{\rm ex}$ is the exciton mass and $D = \hbar \omega_T/m_{\rm ex}$.

The difficulties involved in the calculation of electromagnetic reflection and transmission coefficients for nonlocal media are well known. While there is only one transmitted wave for a local medium, the nonlocal medium has several transmitted waves due to the k dependence in (1) [2]. The Maxwell boundary conditions are no longer sufficient to solve for the unknown amplitudes of the multiple transmitted waves. Historically, this need for extra information was resolved with the introduction of additional boundary conditions (ABCs) on the polarization P associated with the resonances in (1). Various authors [19–42] have proposed different ABCs under certain assumptions that suit different types of materials. The Pekar ABC, where P vanishes at the boundary, is the simplest and most commonly used.

The majority of work on the subject has focused on susceptibilities with a single, isolated resonance. In this case, Halevi and Fuchs [43] have derived reflection coefficients for a generalized ABC model, containing all the previously suggested ABCs. In a previous paper [15], we have adapted this model to the tensor case with different transverse and longitudinal susceptibilities.

In general, the susceptibility of real materials is far more complex than simple isolated resonances [16]. In exciton bands, for example, there can be multiple closely spaced bands, degenerate bands [16,44,45], and more complex k dependence [46–48]. While some authors [49–56] have considered multiresonance systems, they are typically limited to a maximum of two resonances and a specific ABC.

The first aim of this paper is to extend the Halevi and Fuchs [43] generalized ABC model to a multiresonance susceptibility and derive expressions for the reflection and transmission coefficients. This derivation is first applied to a system with simple parabolic exciton bands and then to bands that are degenerate at k = 0, where we find improved parameters for the single-band approximation.

The second aim is to modify the derivation further to include alternate wave-vector dependences, specifically the case where the dispersion in (2) contains a $\pm k$ term. This behavior is known as linear splitting and is typically found in uniaxial crystals such as wurtzite. This case has been previously calculated [54–56], but only for a specific ABC

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and orientation of the crystal axis. We will show that linear k splitting can easily be incorporated into the multiresonance model and that the orientation of the crystal axis has significant effects on the result.

Finally, we will use the derived electromagnetic reflection coefficients to calculate the spectral energy density of thermal and zero-point radiation outside the spatially dispersive medium. The results for various multiresonance systems are calculated and compared to those in our previous paper on the isolated resonance [15].

The assumptions made in the following derivation are discussed in greater detail in our previous paper [15]. In summary, we consider a smooth boundary that does not contain any features such as slits or other nontrivial structures and is sufficiently far from any other boundaries such that multiple reflections can be ignored. In addition, we do not include any quantum mechanical effects that are not directly encoded in the macroscopic susceptibility

The paper is organized as follows. In Sec. II, we present the spatially dispersive susceptibility model for a half-infinite dielectric with a multiresonance permittivity and derive the field equations. In Secs. III and IV, we derive the general expressions for the reflection and transmission coefficients for p and s polarized light, and present the results for parabolic exciton bands in Sec. V. In Sec. VI, we extend our derivation to a uniaxial crystal by including a linear splitting term, and, in Sec. VII, we calculate the zero-point and thermal spectral energy density.

II. THEORY

A. Infinite medium

We first consider an infinite, homogeneous, spatially dispersive dielectric with the susceptibility (1). The electric field E and polarization field P satisfy the wave equation:

$$\nabla \times \nabla \times \boldsymbol{E}(\boldsymbol{r},\omega) - \frac{\omega^2}{c^2} \boldsymbol{E}(\boldsymbol{r},\omega) = \frac{\omega^2}{c^2} \boldsymbol{P}(\boldsymbol{r},\omega), \quad (3)$$

where the polarization field is given by

$$P_i(\mathbf{r},\omega) = \int d^3 \mathbf{r}' \chi(\mathbf{r} - \mathbf{r}',\omega) E_i(\mathbf{r}',\omega). \tag{4}$$

In general, the spatially dispersive susceptibility χ is a tensor [1], but here we consider a scalar. Using the Fourier transformation

$$P_i(\mathbf{r},\omega) = \frac{1}{(2\pi)^3} \int d^3 \mathbf{k} P_i(\mathbf{k},\omega) e^{i\mathbf{k}\cdot\mathbf{r}},$$
 (5)

we have

$$P_i(\mathbf{k},\omega) = \sum_i \chi(\mathbf{k},\omega) E_i(\mathbf{k},\omega). \tag{6}$$

The wave equation (3) has solutions for E when the frequency and wave vector satisfy the dispersion relation [2]

$$(\omega/c)^2[1+\chi(\mathbf{k},\omega)] = k^2, \tag{7}$$

for transverse waves with $\mathbf{E} \cdot \mathbf{k} = 0$, or

$$1 + \chi(\mathbf{k}, \omega) = 0, \tag{8}$$

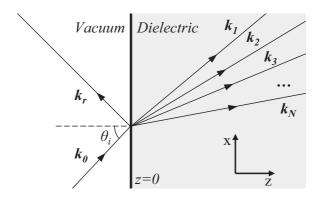


FIG. 1. Schematic of the model. The z < 0 vacuum half space contains the incident (k_0) and reflected (k_r) wave. The angle of incidence is θ_i . The z > 0 spatially dispersive dielectric half space contains M+1 transverse $(k_1, k_2, \ldots, k_{M+1})$ and M longitudinal (k_{M+2}, \ldots, k_N) transmitted waves. The coordinate system is chosen such that the xz plane coincides with the plane of incidence and $k_y = 0$.

for longitudinal waves with $E \times k = 0$. With the field dependence $\exp(ik_z z)$, we restrict ourselves to $\text{Im}[k_z] > 0$, leading to M+1 transverse and M longitudinal waves for the susceptibility in (1) and the parabolic dispersion in (2).

B. Half-infinite medium

We now consider the half-infinite dielectric occupying the z > 0 region, as shown in Fig. 1. The vacuum contains the incident wave (E_0) and reflected wave (E_r) with wave vectors k_0 and k_r ($k_0 = k_r = \omega/c$). Inside the dielectric, there are N = 2M + 1 transmitted waves (E_n) with the corresponding wave vectors k_n . The coordinate system has been chosen such that the xz plane coincides with the plane of incidence, with $k_{nx} = K$, $k_{ny} = 0$, and $k_{nz} = q_n$.

The bulk susceptibility (1) in this coordinate system can be rewritten as

$$\chi(K,0,q) = \chi_0 + \sum_{m=1}^{M} \chi_m(K,0,q), \tag{9}$$

where

$$\chi_m(K, 0, q) = \frac{\omega_{pm}^2 / D_m}{q^2 - \Gamma_m^2(K)}$$
 (10)

and

$$\Gamma_m^2(K) = \frac{\omega^2 - \omega_{Tm}^2 + i\gamma_m\omega}{D_m} - K^2.$$
 (11)

With the presence of the boundary at z = 0, the polarization field now depends on a position-dependent susceptibility χ'_i $(i \in \{x, y, z\})$ [43]. After a Fourier transformation in the xy plane,

$$P_i(K,0,z) = \int_0^\infty dz' \,\tilde{\chi}_i'(K,0,z,z') E_i(K,0,z'). \tag{12}$$

We subsequently omit *K* dependence for notational simplicity. We assume that each resonance in the half-infinite medium can be expressed in terms of the bulk susceptibility in the same

TABLE I. List of ABCs.

	U_x	U_y	U_z
Agarwal <i>et al.</i> [19–28]	0	0	0
Ting <i>et al</i> . [29]	1	1	1
Fuchs-Kliewer [29–33]	1	1	-1
Rimbey-Mahan [34–38]	-1	-1	1
Pekar [39–42]	-1	-1	-1

manner as Halevi and Fuchs [43]:

$$\tilde{\chi}'_{mi}(z,z') = \begin{cases} \tilde{\chi}_m(z-z') + U_{mi}\,\tilde{\chi}_m(z+z') & \text{if } z,z' > 0\\ 0 & \text{otherwise,} \end{cases}$$

and the overall susceptibility is given by

$$\tilde{\chi}_{i}'(z,z') = \begin{cases} \chi_{0}\delta(z-z') + \sum_{m}^{M} \tilde{\chi}_{mi}'(z,z') & \text{if } z,z' > 0\\ 0 & \text{otherwise.} \end{cases}$$
(14)

The first term in (13) is the position-independent nonlocal bulk response. The second describes a polarization wave propagating from z' to the surface before reflecting and continuing to z. The reflection amplitude coefficient U_i is (in general) complex and frequency dependent, with $|U_i|=1$ implying elastic reflection. Halevi and Fuchs [43] demonstrated that specific values of U_i correspond to certain ABCs, shown in Table I. Each ABC was developed for a particular type of medium or excitation. For example, Pekar [39–42] and Rimbey-Mahan [34–38] were developed for Frenkel (tight-binding) excitons, Ting $et\ al.$ [29] for Wannier-Mott (weak-binding) excitons, Fuchs-Kleiwer [29–33] for metals, and Agarwal $et\ al.$ [19–28] for the general case where surface effects can be ignored.

Substituting (14) into (12) gives

$$P_{i}(z) = \chi_{0}E_{i}(z) + \frac{1}{2\pi} \int_{-\infty}^{\infty} dq \int_{0}^{\infty} dz' \sum_{m=1}^{M} [e^{iq(z-z')} + U_{mi}e^{iq(z+z')}]\chi_{m}(q)E_{i}(z'), \quad z > 0.$$
 (15)

At this point, we introduce an ansatz for the E field inside the medium [43]—a linear combination of N = 2M + 1 plane waves from (7) and (8),

$$E_i(z) = \sum_{n=1}^{N} E_i^{(n)} e^{iq_n z},$$
(16)

where n = 1 to M + 1 are transverse waves and n = M + 2 to N are longitudinal waves.

After substitution of the ansatz (16) into (15) and evaluating the z' integral, we find

$$P_{i}(z) = \chi_{0}E_{i}(z) + \frac{i}{2\pi} \int_{-\infty}^{\infty} dq e^{iqz} \sum_{m=1}^{M} \sum_{n=1}^{N} \times \left[\frac{1}{q_{n} - q} + \frac{U_{mi}}{q_{n} + q} \right] \chi_{m}(q) E_{i}^{(n)}, \quad z > 0.$$
 (17)

The q integral is evaluated by performing a contour integration in the upper half plane. This encloses the poles at $q = q_n$ and

 Γ_m , giving

$$P_{i}(z) = \sum_{n=1}^{N} \chi(q_{n}) E_{i}^{(n)} e^{iq_{n}z}$$

$$-\frac{\omega_{p1}^{2}}{2D_{1}\Gamma_{1}} \sum_{n=1}^{N} \left(\frac{1}{q_{n} - \Gamma_{1}} + \frac{U_{1i}}{q_{n} + \Gamma_{1}}\right) E_{i}^{(n)} e^{i\Gamma_{1}z}$$

$$-\frac{\omega_{p2}^{2}}{2D_{2}\Gamma_{2}} \sum_{n=1}^{N} \left(\frac{1}{q_{n} - \Gamma_{2}} + \frac{U_{2i}}{q_{n} + \Gamma_{2}}\right) E_{i}^{(n)} e^{i\Gamma_{2}z} - \cdots$$

$$-\frac{\omega_{pM}^{2}}{2D_{M}\Gamma_{M}} \sum_{n=1}^{N} \left(\frac{1}{q_{n} - \Gamma_{M}} + \frac{U_{Mi}}{q_{n} + \Gamma_{M}}\right) E_{i}^{(n)} e^{i\Gamma_{M}z}.$$
(18)

For the wave equation (3) to be valid for all values of z, we require each of the right-hand-side sums proportional to $\exp(i\Gamma_m z)$ in (18) to equal zero,

$$\sum_{m=1}^{N} \phi_{mi}^{(n)} E_i^{(n)} = 0, \quad m = 1, \dots, M,$$
(19)

where

$$\phi_{mi}^{(n)} = \left(\frac{1}{q_n - \Gamma_m} + \frac{U_{mi}}{q_n + \Gamma_m}\right). \tag{20}$$

This leads to a set of M equations of the form (19) for each of the E_i components.

III. p POLARIZATION

The field can be decomposed to components with E perpendicular to (s-polarized) or in the plane of (p-polarized) incidence. For p-polarized light, $E_y = 0$, $E_x \neq 0$, and $E_z \neq 0$. Both the transverse and longitudinal waves appear in the medium.

A. Surface impedance

The reflection coefficient is calculated using the surface impedance, which for p-polarized light is given by

$$Z_p = \frac{E_x(0^+)}{H_y(0^+)}. (21)$$

(Here, $\mathbf{H} = \mu_0 \mathbf{B}$.) The magnetic field \mathbf{B}_y can be expressed in terms of the electric field using $k_0 \mathbf{B} = \mathbf{k} \times \mathbf{E}$ and (16),

$$B_{y}^{(n)}(z) = \frac{1}{k_{0}} \left[q_{n} E_{x}^{(n)} - K E_{z}^{(n)} \right] e^{i q_{n} z}$$

$$= \left[\frac{q_{n} - K \eta^{(n)}}{k_{0}} \right] E_{x}^{(n)} e^{i q_{n} z}$$

$$= \tau^{(n)} E_{x}^{(n)} e^{i q_{n} z}, \qquad (22)$$

where we have substituted E_x for E_z using

$$E_z^{(n)} = \eta^{(n)} E_x^{(n)}, \tag{23}$$

where $\eta^{(n)} = -K/q_n$ for transverse waves and $\eta^{(n)} = q_n/K$ for longitudinal waves. This leads to

$$\tau^{(n)} = \begin{cases} \frac{q_n^2 + K^2}{q_n k_0} & \text{transverse waves,} \\ 0 & \text{longitudinal waves.} \end{cases}$$
 (24)

The surface impedance can now be expressed solely in terms of E_x field amplitude ratios,

$$Z_{p} = \frac{1}{\mu_{0}} \frac{\sum_{n=1}^{N} E_{x}^{(n)}}{\sum_{n=1}^{N} \tau^{(n)} E_{x}^{(n)}}$$

$$= \frac{1}{\mu_{0}} \frac{1 + \sum_{n=2}^{N} \frac{E_{x}^{(n)}}{E_{x}^{(1)}}}{\tau^{(1)} + \sum_{n=2}^{N} \tau^{(n)} \frac{E_{x}^{(n)}}{E_{x}^{(1)}}}.$$
(25)

B. Field amplitude ratios

To proceed any further, we require the E_x field amplitude ratios in (25). By using (23), we can rewrite the E_z equations in (19) in terms of E_x ,

$$\sum_{n=1}^{N} \left[\phi_{mx}^{(n)} \right] E_{x}^{(n)} = 0, \quad \sum_{n=1}^{N} \left[\eta^{(n)} \phi_{mz}^{(n)} \right] E_{x}^{(n)} = 0.$$
 (26)

We now have 2M equations relating the 2M + 1 waves inside the medium and have sufficient information to solve for the reflection coefficient. After dividing by $E_x^{(1)}$ and rearranging, we can express (26) in matrix form. As an example, we present the result for a two-resonance system:

$$\begin{pmatrix} \phi_{1x}^{(2)} & \phi_{1x}^{(3)} & \phi_{1x}^{(4)} & \phi_{1x}^{(5)} \\ \phi_{2x}^{(2)} & \phi_{2x}^{(3)} & \phi_{2x}^{(4)} & \phi_{2x}^{(5)} \\ \eta^{(2)}\phi_{1z}^{(2)} & \eta^{(3)}\phi_{1z}^{(3)} & \eta^{(4)}\phi_{1z}^{(4)} & \eta^{(5)}\phi_{1z}^{(5)} \\ \eta^{(2)}\phi_{2z}^{(2)} & \eta^{(3)}\phi_{2z}^{(3)} & \eta^{(4)}\phi_{2z}^{(4)} & \eta^{(5)}\phi_{2z}^{(5)} \end{pmatrix} \begin{pmatrix} E_x^{(2)}/E_x^{(1)} \\ E_x^{(3)}/E_x^{(1)} \\ E_x^{(4)}/E_x^{(1)} \\ E_x^{(4)}/E_x^{(1)} \\ E_x^{(5)}/E_x^{(1)} \end{pmatrix}$$

$$= -\begin{pmatrix} \phi_{1x}^{(1)} \\ \phi_{2x}^{(1)} \\ \eta^{(1)}\phi_{2z}^{(1)} \\ \eta^{(1)}\phi_{2z}^{(1)} \end{pmatrix}, \tag{27}$$

where n = 1,2,3 are transverse waves and n = 4,5 are longitudinal waves. By inverting the $2M \times 2M$ matrix, we can find the field amplitude ratios.

C. Reflection and transmission coefficients

The *p*-polarization reflection coefficient can be expressed in terms of surface impedance [30],

$$r_p = \frac{E_r}{E_0} = \frac{Z_p^{(0)} - Z_p}{Z_p^{(0)} + Z_p},\tag{28}$$

where Z_p is given by (25) and $Z_p^{(0)} = \sqrt{k_0^2 - K^2}/\mu_0 k_0$ is the vacuum surface impedance.

We can find the transmission coefficients for the N transmitted waves by imposing the continuity of the tangential E field across the boundary. Our choice of coordinate system

means we simply equate the E_x components on each side,

$$[E_0 - E_r] \cos \theta_i = \left[\sum_{n=1}^N E_x^{(n)} \right].$$
 (29)

This can be expressed in terms of the previously calculated field amplitude ratios using (28) and $\cos \theta_i = \sqrt{k_0^2 - K^2}/k_0$:

$$\frac{\sqrt{k_0^2 - K^2}}{k_0} [1 - r_p] E_0 = \left[1 + \sum_{x=2}^{N} \frac{E_x^{(n)}}{E_x^{(1)}} \right] E_x^{(1)}.$$
 (30)

By rewriting

$$E^{(n)} = \sqrt{\left[E_x^{(n)}\right]^2 + \left[E_z^{(n)}\right]^2} = \sqrt{1 + \eta^{(n)2}} E_x^{(n)}, \quad (31)$$

we can derive the transmission coefficient,

$$t_p^{(n)} = \frac{E^{(n)}}{E_0},\tag{32}$$

for transverse waves.

$$t_p^{(n)} = \frac{\sqrt{q_n^2 + K^2}}{q_n} \frac{E_x^{(n)}}{E_x^{(1)}} \frac{\sqrt{k_0^2 - K^2}}{k_0} \frac{[1 - r_p]}{[1 + \sum_{n=2}^N \frac{E_x^{(n)}}{E^{(1)}}]}, \quad (33)$$

and longitudinal waves,

$$t_p^{(n)} = \frac{\sqrt{q_n^2 + K^2}}{K} \frac{E_x^{(n)}}{E_x^{(1)}} \frac{\sqrt{k_0^2 - K^2}}{k_0} \frac{[1 - r_p]}{[1 + \sum_{n=2}^{N} \frac{E_x^{(n)}}{E^{(1)}}]}.$$
 (34)

We now have a single method for r_p and t_p in the presence of multiple resonances that can cover a wide frequency range. This derivation could be extended further to a tensor susceptibility using the method described in our previous paper [15]. In this case, the polarization reflection coefficients are a tensor U_{ij} with certain restrictions on the components.

IV. s POLARIZATION

We now consider the simpler case of s-polarized light, where $E_y \neq 0$, $E_x = 0$, and $E_z = 0$. As k_n all lie in the xz plane, this leads to the absence of longitudinal waves in the medium, leaving the M+1 transverse waves.

A. Surface impedance

The surface impedance for s-polarized light is given by

$$Z_s = -\frac{E_y(0^+)}{H_v(0^+)}. (35)$$

As in (25), we express H_x in terms of E_y and field amplitude ratios,

$$Z_{s} = \frac{1}{\mu_{0}} \frac{k_{0} \sum_{n=1}^{M+1} E_{y}^{(n)}}{\sum_{n=1}^{M+1} q_{n} E_{y}^{(n)}} = \frac{1}{\mu_{0}} k_{0} \frac{1 + \sum_{n=2}^{M+1} \frac{E_{y}^{(n)}}{E_{y}^{(1)}}}{q_{1} + \sum_{n=2}^{M+1} q_{n} \frac{E_{y}^{(n)}}{E_{y}^{(1)}}}.$$
 (36)

As we only have the M+1 transverse waves in the s polarization, the set of M equations from (19) can be rewritten as

$$\sum_{n=2}^{M+1} \left[\phi_{my}^{(n)} \right] \frac{E_y^{(n)}}{E_y^{(1)}} = -\phi_{my}^{(1)}, \tag{37}$$

which is sufficient to solve for the amplitude ratios.

B. Reflection and transmission coefficients

Using the vacuum surface impedance $Z_s^{(0)} = k_0/\mu_0\sqrt{k_0^2-K^2}$ and (36), we can construct the *s*-polarization reflection coefficient,

$$r_s = \frac{E_r}{E_0} = \frac{Z_s^{(0)} - Z_s}{Z_s^{(0)} + Z_s}. (38)$$

As in the previous section, we impose the continuity of the tangential E field across the boundary. As we only have E_y components, this leads to

$$E_0 - E_r = \sum_{n=1}^{M+1} E_y^{(n)}.$$
 (39)

Using (38), this can be expressed in terms of the field amplitude ratios previously found from (37),

$$E_0(1 - r_s) = E_y^{(1)} \left(1 + \sum_{n=2}^{M+1} \frac{E_y^{(n)}}{E_y^{(1)}} \right), \tag{40}$$

which leads to

$$t_s^{(n)} = \frac{E^{(n)}}{E_0} = \frac{E_y^{(n)}}{E_y^{(1)}} \frac{1 - r_s}{1 + \sum_{n=2}^{M+1} \frac{E_y^{(n)}}{E_y^{(1)}}}.$$
 (41)

V. REFLECTION COEFFICIENT RESULTS

We now use the derivations in the previous sections for a number of materials with a variety of exciton band structures. In Fig. 2, we show some example exciton bands and the corresponding dispersion relations for transverse E waves in the absence of damping.

In this section, we first consider the simple case of ZnO [50] with three noninteracting exciton bands and GaAs [52] with two bands that are degenerate at k=0. The model parameters are given in Table II. The values of ω_p are calculated from the measured values of ω_L , which are the solutions of the

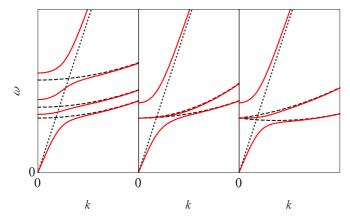


FIG. 2. Exciton band behavior (black dashed line) compared to the light line (black dotted line) and dispersion relations for transverse E waves in an infinite medium (solid red line) when γ is set to zero. Examples include multiple parabolic bands (left), heavy/light exciton bands with the same ω_T but different k^2 terms (middle), and bands with the same ω_T and k^2 terms, but a $\pm k$ linear splitting term (right). The exciton bands in last two are degenerate at k=0.

TABLE II. List of model parameters.

	ZnO [50]			GaAs [52]	
m	1	2	3	1	2
χο	5.2	5.2	5.2	11.6	11.6
$\hbar\omega_T \text{ (eV)}$	3.3758	3.3810	3.4198	1.514	1.514
$\hbar\omega_L$ (eV)	3.3776	3.3912	3.4317	1.515	1.515
ħγ (meV)	0.7	0.7	0.7	0.05	0.05
$m_{\rm ex} (m_{\rm ex})$	0.87	0.87	0.87	0.183	0.805
$\hbar\omega_{p}$ (eV)	0.5334	0.6055	0.5983	0.138	0.138
$D (10^{11} \mathrm{m^2 s^{-2}})$	6.82	6.84	6.91	14.55	3.31

dispersion relation for transverse E waves at k = 0 in the absence of damping. Similarly, D is found from the measured exciton mass $m_{\rm ex}$, which is given in units of the rest electron mass $m_{\rm e0}$.

A. Simple resonances

We first consider a three-resonance model for ZnO [50], involving the A, B, and C excitons which we label m=1,2, and 3, respectively. The exciton bands are of the form in (2) and do not interact.

Figure 3 shows $r_p(\omega)$ and $r_s(\omega)$ for a fixed incident angle. The peak locations are determined by the ω_T and ω_L values, indicated by solid and dashed vertical lines, respectively. The r_p behavior is mostly determined by U_x , with $U_x = 1$ giving the largest maxima and smallest minima. In contrast, U_z only affects the results at the reflection minima. The frequency region around ω_{T3} can be accurately described using the single-resonance model. This is because the overlap with the other resonances in the susceptibility is very small. The same is not true of the m=1 and 2 resonances. Here the proximity

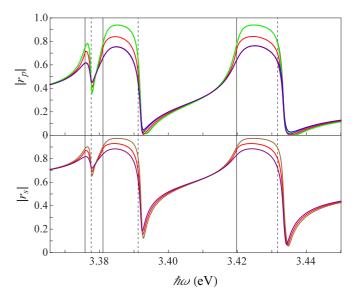


FIG. 3. Reflection coefficients r_p and r_s as a function of ω for the ZnO three-exciton model at an incident angle of 60° . Vertical lines indicate ω_{Tm} (solid line) and ω_{Lm} (dashed line) values. Includes Agarwal *et al.* (red), Ting *et al.* (brown), Fuchs-Kliewer (green), Rimbey-Mahan (blue), and Pekar (purple) ABCs.

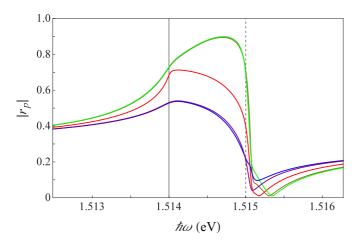


FIG. 4. Reflection coefficient r_p as a function of ω for the GaAs heavy/light exciton model at an incident angle of 60° . Vertical lines indicate ω_T (solid line) and ω_L (dashed line) values. Plot styles follow the conventions in Fig. 3.

of ω_{T1} and ω_{T2} leads to the one-resonance model's failing, particularly in the intermediate-frequency region. The effect of U_i remains the same as the isolated resonance. However, if there is significant overlap in the resonant peaks (e.g., if the ω_T values are separated by less that the full width at half maximum), then $U_x = 1$ gives not only the largest peaks, but also the largest value in the intermediate-frequency region.

B. Heavy and light excitons

We now move on to consider an exciton band structure with degeneracy at k = 0. Kane [44] showed that interactions in a medium could lead to the splitting of degenerate exciton bands. In the case of isotropic valence bands, this can lead to a "heavy" and "light" exciton band with parabolic dispersion relations

$$\omega_{Th}^2(k) = \omega_T^2 + \frac{\hbar \omega_T}{m_h} k^2 = \omega_T^2 + D_h k^2,$$
 (42)

$$\omega_{T1}^{2}(k) = \omega_{T}^{2} + \frac{\hbar \omega_{T}}{m_{1}} k^{2} = \omega_{T}^{2} + D_{1}k^{2}$$
 (43)

substituted into the susceptibility.

We consider a two-resonance model for GaAs [52] containing only the heavy and light exciton bands, using the parameters in Table II. We have slightly simplified the model by assuming isotropic valence bands and using the $\langle 100 \rangle$ exciton masses for all directions. The results for r_p are shown in Fig. 4 and display the same basic features as a single-resonance model. The same behavior is seen in the r_s result, which we do not plot.

Previous work [52] has suggested that the two-resonance system of heavy and light exciton bands can be approximated by a single band with an effective $D_{\rm eff}$ term in the susceptibility, given by

$$D_{\rm eff} = \frac{D_{\rm h} + D_{\rm l}}{2},\tag{44}$$

and multiplying ω_p^2 by a factor of 2. However, simply taking the average of the nonlocal parameter D as in (44) does not lead

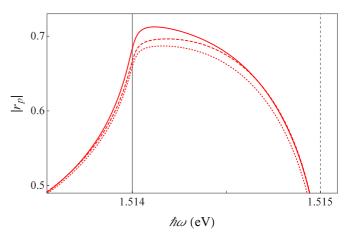


FIG. 5. Detail of r_p using the Agarwal *et al.* ABC for the GaAs heavy/light exciton model (solid line) compared to effective one-exciton results. We find that D^* (dashed line) from (46) gives a better fit to the resonant peak than the previously suggested $D_{\rm eff}$ (dotted line) from (44).

to the best approximation. Figure 5 compares the heavy/light exciton model to the effective single-band result and shows that it underestimates the peak of the heavy/light system. This is true even when $D_{\rm h}$ and $D_{\rm l}$ are close. Instead, if we reexpress the nonlocal term as

$$D^*k^2 = (\sigma k)^2, (45)$$

we find that a better fit is given by taking the average value of the coefficient σ , which leads to

$$\sqrt{D^*} = \frac{\sqrt{D_h} + \sqrt{D_l}}{2}.\tag{46}$$

This new value provides an excellent fit when D_1 and D_h have similar values. For larger differences between D_1 and D_h (such as this model, where $D_1 \approx 4D_h$), both single-resonance approximations begin to fail as the two-resonance model has a larger peak just above ω_T . This difference is greatest for $U_x = -1$ and smallest for $U_x = 1$. Despite this, we find that (46) gives a better fit to r_p and r_s than (44) for all values of $D_{1/h}$ and U_i .

VI. LINEAR k TERMS

So far we have only considered materials with isotropic, parabolic energy bands of the form (2). However, the symmetry of the crystal structure can lead to the introduction of additional k terms. For example, in 1964, Mahan and Hopfield [54] used a linear k term to explain a shoulder in the reflection spectra of CdS, a uniaxial medium with wurtzite crystal symmetry. This behavior was only observed when E was perpendicular to the crystal axis c, with the exciton dispersion relation

$$\hbar\omega_{\pm}(\mathbf{k}) = \hbar\omega_{T} + \frac{\hbar^{2}k_{\perp}^{2}}{2m_{\mathrm{ex}\perp}} + \frac{\hbar^{2}k_{\parallel}^{2}}{2m_{\mathrm{ex}\parallel}} \pm \zeta k_{\perp}, \tag{47}$$

where $m_{\rm ex}$ is the exciton mass, and k_{\parallel} and k_{\perp} are wave-vector components parallel and perpendicular to c, respectively. In the susceptibility, (47) is approximated to [54],

$$\omega_{\pm}^{2}(\mathbf{k}) = \omega_{T}^{2} + D_{\perp}k_{\perp}^{2} + D_{\parallel}k_{\parallel}^{2} \pm \xi k_{\perp}, \tag{48}$$

TABLE III. List of χ_{liny} expressions for c orientations.

	Xliny
$c \parallel \hat{x}$	$\frac{2\omega_p^2(\omega_T^2+D_\perp q^2+D_\parallel K^2-\omega^2-i\gamma\omega)}{(\omega_T^2+D_\perp q^2+D_\parallel K^2-\omega^2-i\gamma\omega)^2-\xi^2q^2}$
$c\parallel\hat{y}$	$rac{2\omega_p^2}{[\omega_T^2+D_\perp(K^2+q^2)]-\omega^2-i\gamma\omega}$
$c\parallel\hat{z}$	$\frac{2\omega_p^2(\omega_T^2+D_\perp K^2+D_\parallel q^2-\omega^2-i\gamma\omega)}{(\omega_T^2+D_\perp K^2+D_\parallel q^2-\omega^2-i\gamma\omega)^2-\xi^2K^2}$

where $D_{\perp/\parallel} = \hbar \omega_T / m_{\rm ex\perp/\parallel}$ and $\xi = 2\omega_T \zeta / \hbar$. This leads to two resonances,

$$\chi_{+}(\mathbf{k}) + \chi_{-}(\mathbf{k}) = \frac{\omega_{p}^{2}}{\left(\omega_{T}^{2} + D_{\perp}k_{\perp}^{2} + D_{\parallel}k_{\parallel}^{2} + \xi k\right) - \omega^{2} - i\gamma\omega} + \frac{\omega_{p}^{2}}{\left(\omega_{T}^{2} + D_{\perp}k_{\perp}^{2} + D_{\parallel}k_{\parallel}^{2} - \xi k\right) - \omega^{2} - i\gamma\omega}, \quad (49)$$

which can be collected to a single fraction χ_{lin}^{\perp} , giving

$$\chi_{\text{lin}}^{\perp}(\mathbf{k}) = \frac{2\omega_p^2 \left(\omega_T^2 + D_{\perp} k_{\perp}^2 + D_{\parallel} k_{\parallel}^2 - \omega^2 - i\gamma\omega\right)}{\left(\omega_T^2 + D_{\perp} k_{\perp}^2 + D_{\parallel} k_{\parallel}^2 - \omega^2 - i\gamma\omega\right)^2 - \xi^2 k_{\perp}^2}$$
(50)

for $E \perp c$. When $E \parallel c$, the exciton bands were found to be degenerate with $\zeta = 0$, leading to the resonance

$$\chi_{\text{lin}}^{\parallel}(\mathbf{k}) = \frac{2\omega_p^2}{\left(\omega_T^2 + D_{\perp}k_{\perp}^2 + D_{\parallel}k_{\parallel}^2\right) - \omega^2 - i\gamma\omega}.$$
 (51)

The bulk susceptibility of the uniaxial crystal is no longer a scalar and takes a vector form when c is aligned with one of the coordinate axes, such as

$$\chi_{\text{lin}}(\mathbf{k}) = \begin{pmatrix} \chi_{\text{lin}}^{\perp}(\mathbf{k}) \\ \chi_{\text{lin}}^{\perp}(\mathbf{k}) \\ \chi_{\text{lin}}^{\parallel}(\mathbf{k}) \end{pmatrix}$$
(52)

for $c \parallel \hat{z}$. In Tables III and IV, we present the $\chi_{\text{lin}i}$ components relevant for s- and p-polarized light when c is aligned with each of the coordinate axes as defined in Fig. 1.

Previous work [54–56] has only considered such a model for $c \parallel \hat{y}$ (perpendicular to the incident plane) using the Pekar ABC. We will now modify the derivation of the

previous section to include resonances of the form (52) in a multiresonance system with arbitrary U values when c is aligned with each of the coordinate axes.

A. Field amplitude ratios

Due to the fact that the bulk components in (52) are no longer equal, the dispersion relations take the form

$$k_0^2[1 + \chi_{\text{linv}}(q)] - (K^2 + q^2) = 0$$
 (53)

for s-polarized light, and

$$k_0^2[1 + \chi_{\text{lin}x}(q)][1 + \chi_{\text{lin}z}(q)] - K^2[1 + \chi_{\text{lin}x}(q)] - q^2[1 + \chi_{\text{lin}z}(q)] = 0$$
(54)

for *p*-polarized light, where we have omitted *K* dependence for notational simplicity. Unlike the previous section, the results of (53) are not also solutions of (54). We substitute the susceptibility (50) and (51) and the ansatz (16) into (15), using the *N* values of q_n that satisfy (53) and (54). If the field is aligned with c, there is no linear splitting and the derivation in the previous section is sufficient to find the amplitude ratios. If linear splitting is present, then $\chi_{\text{lin}i}$ has two poles with Im[q] > 0, which we label $\Gamma_i^{(+)}$ and $\Gamma_i^{(-)}$. Evaluating the contour integral in (17) gives

$$P_{i}(z) = \sum_{n=1}^{N} \chi_{\text{lin}i}(q_{n}) E_{i}^{(n)} e^{iq_{n}z}$$

$$-F_{i}^{(+)} \sum_{n=1}^{N} \left(\frac{1}{q_{n} - \Gamma_{i}^{(+)}} + \frac{U_{\text{lin}i}}{q_{n} + \Gamma_{i}^{(+)}} \right) E_{i}^{(n)} e^{i\Gamma_{i}^{(+)}z}$$

$$-F_{i}^{(-)} \sum_{n=1}^{N} \left(\frac{1}{q_{n} - \Gamma_{i}^{(-)}} + \frac{U_{\text{lin}i}}{q_{n} + \Gamma_{i}^{(-)}} \right) E_{i}^{(n)} e^{i\Gamma_{i}^{(-)}z},$$
(55)

where $F_i^{(\pm)}$ is a simple prefactor and we have used a single value of $U_{\text{lin}i}$ for both resonances. The additional terms not proportional to $\exp(iq_nz)$ lead to the same set of equations as (19), but with different values of Γ_m :

$$\sum_{n=1}^{N} \left(\frac{1}{q_n - \Gamma_i^{(+)}} + \frac{U_{\text{lin}i}}{q_n + \Gamma_i^{(+)}} \right) E_i^{(n)} = 0,$$

$$\sum_{n=1}^{N} \left(\frac{1}{q_n - \Gamma_i^{(-)}} + \frac{U_{\text{lin}i}}{q_n + \Gamma_i^{(-)}} \right) E_i^{(n)} = 0.$$
(56)

TABLE IV. List of χ_{linx} and χ_{linz} expressions for c orientations.

	Xlinx	Xlinz
$c \parallel \hat{x}$	$rac{2\omega_p^2}{(\omega_T^2+D_\perp q^2+D_\parallel K^2)-\omega^2-i\gamma\omega}$	$rac{2\omega_p^2(\omega_T^2+D_\perp q^2+D_\parallel K^2-\omega^2-i\gamma\omega)}{(\omega_T^2+D_\perp q^2+D_\parallel K^2-\omega^2-i\gamma\omega)^2-\xi^2q^2}$
$c\parallel\hat{y}$	$\frac{2\omega_{p}^{2}[\omega_{T}^{2}+D_{\perp}(K^{2}+q^{2})-\omega^{2}-i\gamma\omega]}{[\omega_{T}^{2}+D_{\perp}(K^{2}+q^{2})-\omega^{2}-i\gamma\omega]^{2}-\xi^{2}(K^{2}+q^{2})}$	$\frac{2\omega_{p}^{2}[\omega_{T}^{2}+D_{\perp}(K^{2}+q^{2})-\omega^{2}-i\gamma\omega]}{[\omega_{T}^{2}+D_{\perp}(K^{2}+q^{2})-\omega^{2}-i\gamma\omega]^{2}-\xi^{2}(K^{2}+q^{2})}$
$c\parallel\hat{z}$	$rac{2\omega_p^2(\omega_T^2+D_\perp K^2+D_\parallel q^2-\omega^2-i\gamma\omega)}{(\omega_T^2+D_\perp K^2+D_\parallel q^2-\omega^2-i\gamma\omega)^2-\xi^2K^2}$	$rac{2\omega_p^2}{(\omega_T^2+D_\perp K^2+D_\parallel q^2)-\omega^2-i\gamma\omega}$

TABLE V. List of model parameters.

	CdS [16]
	Cus [10]
Χο	6.5
$\hbar\omega_T$ (eV)	2.5674
$\hbar\omega_L$ (eV)	2.5688
$\hbar \gamma \; (\text{meV})$	0.075
$m_{\rm ex} \ (m_{\rm ex})$	$1.3 \; (\perp c), \; 1.02 \; (\parallel c)$
ζ (eV m)	5.6×10^{-12}
$\hbar\omega_p$ (eV)	0.164
$D(10^{11} \mathrm{m}^2\mathrm{s}^{-2})$	$3.47 (\perp c), 4.43 (\parallel c)$
$\xi (m s^{-2})$	6.637×10^{19}

In summary, the inclusion of linear k terms to the exciton dispersion relation does not significantly affect the derivation of field amplitude ratios presented in the previous section. The only changes required are to use the appropriate Γ values in the field amplitude ratio matrix and the q values that satisfy the dispersion relation.

B. $c \parallel \hat{y}$ orientation

The simplest case is to align the crystal axis c with \hat{y} . This particular orientation has been looked at previously for the Pekar ABC. As there is no linear splitting in χ_{liny} for this orientation, the derivation in the previous section is sufficient to calculate r_s and $t_s^{(n)}$ in the s polarization. The χ_{liny} term leads to two transverse waves from (53), if it is the only resonance.

In comparison, $\chi_{\text{lin}x}$ and $\chi_{\text{lin}z}$ are equal and contain linear splitting. Equation (54) for the *p* polarization can be simplified to

$$[1 + \chi_{\text{lin}x}(q)] \{ k_0^2 [1 + \chi_{\text{lin}x}(q)] - (K^2 + q^2) \} = 0.$$
 (57)

Solutions of the first bracket give two longitudinal waves and the second give three transverse waves, for a total of five if χ_{lin} is the only resonance. The transverse waves are no longer the same as those in the *s* polarization.

As $\chi_{\text{lin}x}$ and $\chi_{\text{lin}z}$ contain linear splitting, the integral in (17) leads to two equations of the form (56) for both E_x and E_z . The E_z equations can be converted to E_x using (23) with $\eta^{(n)} = -K/q_n$ for transverse waves and $\eta^{(n)} = q_n/K$ for longitudinal waves, as in the previous section. This gives a total of four E_x equations, the same as the number of transmitted waves added by the resonance, which is sufficient to solve for the reflection coefficient.

C. $c \parallel \hat{x}$ or $c \parallel \hat{z}$ orientation

The two other orientations present additional challenges. As splitting is present in $\chi_{\text{lin}y}$, the *s* polarization now has three transverse waves, and two equations of the form (56) for E_y . There is sufficient information to solve for r_s and $t_s^{(n)}$.

The fact that the expressions for χ_{linx} and χ_{linz} in Table IV are different means (54) cannot be simplified and the waves are no longer purely transverse or longitudinal. The χ_{lin} resonances give a total of four waves in the absence of other resonances. The contour integration in (17) leads to a total of three equations of the form (56)—one from the unsplit χ_{lini} and two from the split χ_{lini} . Again, we have sufficient information to solve for the field amplitude ratios.

As the waves are no longer purely transverse or longitudinal, care must be taken when converting E_z to E_x . From the wave equation, we find

$$\eta^{(n)} = -\frac{1}{Kq_n} \left\{ k_0^2 [1 + \chi_{\text{lin}x}(q_n)] - q_n^2 \right\}.$$
 (58)

Similarly, the relation between B_y and E_x used in (25) is modified from (24) to

$$\tau^{(n)} = \left\lceil \frac{q_n - K \eta^{(n)}}{k_0} \right\rceil = \frac{k_0}{q_n} [1 + \chi_{\text{lin}x}(q_n)].$$
 (59)

These expressions and the calculated field amplitude ratios are substituted into (25) and (36) to find the surface impedances and the subsequent reflection coefficients.

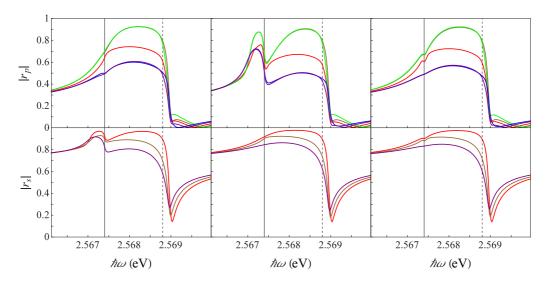


FIG. 6. Reflection coefficients r_p and r_s as a function of ω at an incident angle of 60° with the crystal axis c aligned with \hat{x} (left), \hat{y} (middle), and \hat{z} (right). Vertical lines indicate ω_T (solid line) and ω_L (dashed line) values. Plot styles follow the conventions in Fig. 3.

D. Results

As an example, we present the results for CdS [16] using the model parameters in Table V, where ξ in (47) has been calculated from the measured ζ in (48). Figure 6 shows $r_p(\omega)$ and $r_s(\omega)$ at an incident angle of 60° for c aligned with \hat{x} , \hat{y} , and \hat{z} .

As expected, the $c \parallel \hat{y}$ result for r_p is significantly different from the others due to linear splitting in both the $\chi_{\text{lin}x}$ and $\chi_{\text{lin}z}$ components used for p-polarized light. This leads to an additional peak in r_p below ω_T . While the behavior of the new peak is still mostly determined by the value of U_x , the order in which the ABCs appear is different to that of the previous section where $U_x = 1$ is the largest and $U_x = -1$ is the smallest. The r_s result for $c \parallel \hat{y}$ is identical to that of the previous section as there is no splitting in $\chi_{\text{lin}y}$ for this orientation.

The $c \parallel \hat{x}$ and $c \parallel \hat{z}$ cases have splitting in only one component of $\chi_{\text{lin}i}$ for p-polarized light, resulting in an r_p that is closer to the $\xi = 0$ result but also displays new features just below ω_T at a smaller scale. The $c \parallel \hat{z}$ results for r_p and r_s are the closest to the $\xi = 0$ case as the linear term in Table IV only contains K. As θ_i (and K) is decreased, the peak at ω_T becomes smaller, returning to the $\xi = 0$ result for normal incidence. As in the previous section, the new peak is unaffected by U_z and is larger for $U_x = 1$. In contrast, the $c \parallel \hat{x}$ case has q in the linear splitting term. The differences in the r_p result are similar in magnitude to the $c \parallel \hat{z}$ case, but the new peak at ω_T is more pronounced for $U_x = -1$ and is now affected by the value of U_z . The effect of the splitting in q is even more pronounced in r_s , which displays features similar to r_p in the $c \parallel \hat{y}$ case. This is because the linear splitting in q is present in *every* χ_{lini} term used in their derivation.

In all cases, the difference between m_{\perp} and m_{\parallel} has very little effect compared to the choice of ABC. This agrees with our previous work on the tensor susceptibility [15].

VII. SPECTRAL ENERGY DENSITY

We now focus on the electromagnetic zero point and thermal radiation at a perpendicular distance |z| from the boundary of the nonlocal medium. In our previous paper on the one-resonance system [15], we found that the inclusion of spatial dispersion removed the unphysical $1/|z|^3$ divergence present in the spectral energy density of the local model [57,58]. We now investigate how the behavior of the materials considered in the previous sections changes due to the presence of multiple resonances.

The average energy density of the electromagnetic zero point and thermal radiation in the vacuum outside a medium is given by [59]

$$\langle U \rangle = \frac{\varepsilon_0}{2} \langle |\boldsymbol{E}(\boldsymbol{r}, t)|^2 \rangle + \frac{\mu_0}{2} \langle |\boldsymbol{B}(\boldsymbol{r}, t)|^2 \rangle$$
$$= \int_0^\infty d\omega \, u_{\text{tot}}(z, \omega), \tag{60}$$

where $u_{\text{tot}}(z,\omega)$ is the spectral energy density. Assuming that the nonlocal medium is in thermal equilibrium with its surroundings and the system is rotationally invariant around the z axis, this can be written in terms of the previously

calculated reflection coefficients,

$$u_{\text{tot}}(z,\omega) = \frac{u_0}{k_0} \int_0^{k_0} \frac{KdK}{\sqrt{k_0^2 - K^2}} \times \left\{ 1 + \frac{K^2 \text{Re}[(r_s + r_p)e^{2i\sqrt{K^2 - k_0^2}|z|}]}{2k_0^2} \right\} + \frac{u_0}{2k_0^3} \int_{k_0}^{\infty} \frac{K^3 dK}{\sqrt{K^2 - k_0^2}} \text{Im}[r_s + r_p]e^{-2\sqrt{K^2 - k_0^2}|z|}.$$
(61)

The first integral in (61) is the contribution of propagating waves, while the second comes from evanescent waves. The term u_0 is the spectral energy density in the absence of the material, given by

$$u_0 = \frac{\Theta(\omega, T)\omega^2}{\pi^2 c^3},\tag{62}$$

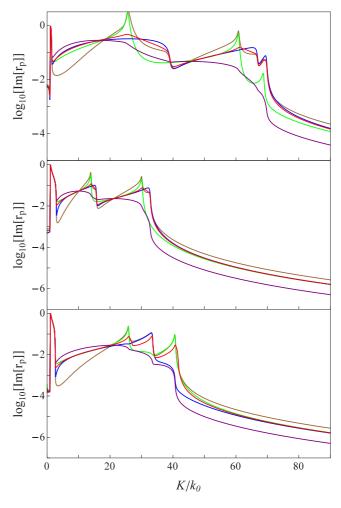


FIG. 7. Comparison of ${\rm Im}[r_p]$ as a function of K for evanescent waves in ZnO at $\hbar\omega=3.44~{\rm eV}$ (top), GaAs at $\hbar\omega=1.517~{\rm eV}$ (middle), and CdS ($\hat{z}\parallel c$) at $\hbar\omega=2.573~{\rm eV}$ (bottom). Plot styles follow the conventions in Fig. 3.

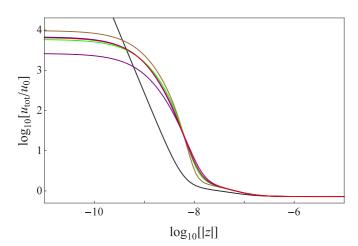


FIG. 8. Behavior of $u_{\rm tot}$ as a function of distance |z| from the boundary of ZnO at $\hbar\omega=3.44$ eV compared to the $1/z^3$ divergent result of the local model (black line). Plot styles follow the conventions in Fig. 3.

where the mean energy of a harmonic oscillator in thermal equilibrium is

$$\Theta(\omega, T) = \hbar \omega \left(\frac{1}{2} + \frac{1}{e^{\hbar \omega / k_B T} - 1} \right). \tag{63}$$

The first term of (63) gives rise to the electromagnetic zero-point energy.

In the $K \to \infty$ limit for the local medium, $r_s \to 0$ and $r_p \to \chi(\omega)/[2 + \chi(\omega)]$, leading to the divergent result for the second integral [59],

$$\frac{1}{4|z|^3} \frac{\mathrm{Im}[\chi(\omega)]}{|2 + \chi(\omega)|^2}.$$
 (64)

In our previous paper, we showed that the inclusion of spatial dispersion leads to peaks in $\text{Im}[r_p]$ near the point where the $\text{Re}[\Gamma^2]$ changed sign from positive to negative, followed by a $1/K^4$ decay in the large-K limit. In Fig. 7, we find the same behavior for ZnO, GaAs, and CdS ($\hat{z} \parallel c$), with a peak for every Γ_m value.

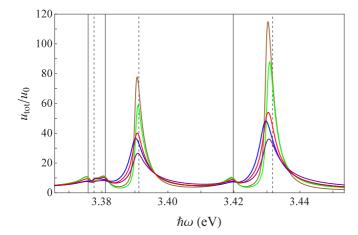


FIG. 9. Behavior of u_{tot} at a fixed distance of 8 nm from the boundary of ZnO. Vertical lines indicate ω_{Tm} (solid line) and ω_{Lm} (dashed line) values. Plot styles follow the conventions in Fig. 3.

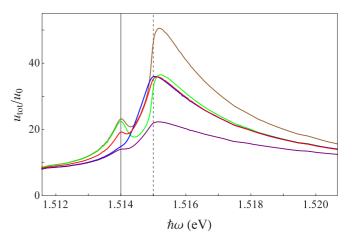


FIG. 10. Behavior of u_{tot} at a fixed distance of 8 nm from the boundary of GaAs. Vertical lines indicate ω_T (solid line) and ω_L (dashed line) values. Plot styles follow the conventions in Fig. 3.

Figure 8 shows the z dependence of u_{tot} for ZnO at $\hbar\omega=3.44$ eV. The behavior is the same as found in our previous paper—the $1/|z|^3$ divergence is removed and u_{tot} saturates to a finite value. The ABC behavior is similar, with Ting *et al.* giving the largest result; Fuchs-Kleiwer, Rimbey-Mahan, and Agarwal *et al.* have similar intermediate values and Pekar is the smallest. The other materials display the same behavior and so are omitted here.

The main differences to the one-resonance model are found in the ω dependence of u_{tot} at a fixed distance from the boundary. We first consider the simple case of ZnO, with multiple, nonintersecting parabolic exciton bands. Figure 9 shows $u_{\text{tot}}(\omega)$ at a distance of 8 nm from the boundary. The results are strongly dependent on the choice of ABC, with Ting $et\ al$. giving the largest peaks, followed by Fuchs-Kleiwer, Agarwal $et\ al$., Rimbey-Mahan, and finally Pekar. This behavior agrees with our previous paper [15]. Each resonance has two associated peaks in $u_{\text{tot}}(\omega)$, for a total of six. The peaks in u_{tot} near ω_{Tm} are due to the s-polarization contribution to the integral and the peaks at ω_{Lm} are due to

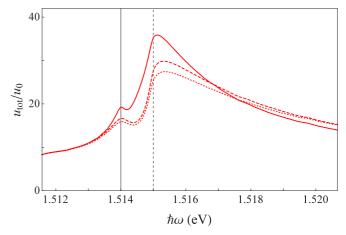


FIG. 11. Detail of the Agarwal *et al.* ABC in Fig. 10 for the heavy/light exciton model compared to the one-exciton results for D^* (dashed line) and $D_{\rm eff}$ (dotted line).

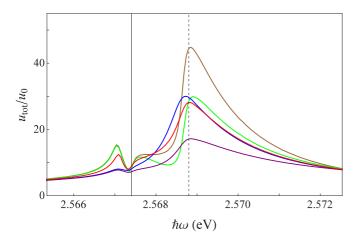


FIG. 12. Behavior of u_{tot} at a fixed distance of 8 nm from the boundary of CdS. Vertical lines indicate ω_T (solid line) and ω_L (dashed line) values. Plot styles follow the conventions in Fig. 3.

the *p*-polarization contribution. In the one-resonance system, the *s*-polarization peaks in u_{tot} were typically much smaller than their *p*-polarization counterparts. However, the u_{tot} peak at ω_{L1} has been suppressed due to the proximity of the peak at ω_{L2} and is now comparable in size to the *s*-polarization peaks. This can be seen in Fig. 7, where the peak in $\text{Im}[r_p]$ associated with Γ_1 and the m=1 resonance at the largest K value is very small due to the presence of the nearby Γ_2 peak at a smaller K value.

We next consider the heavy/light exciton model of GaAs. Figure 10 shows $u_{\text{tot}}(\omega)$ at a distance of 8 nm from the boundary. At first glance, the results appear similar to those of the single-resonance model, but the comparison in Fig. 11 reveals that both the D^* and D_{eff} single-exciton models both underestimate the peak values. This is due to the behavior of r_p . While both approximations provide a good fit for propagating waves, u_{tot} depends more on the evanescent wave contribution at small distances. Both approximations have a single peak in $\text{Im}[r_p]$ at large K in contrast to the two peaks of the heavy/light exciton model in Fig. 7.

We finally consider the uniaxial crystal of CdS in the $c \parallel \hat{z}$ case, as the other orientations lack the rotational invariance about the z axis required for Eq. (61). The underlying behavior behind Fig. 12 is more complex than the previous cases with k^2 dispersion. There are now two peaks in each of the s- and p-polarization contributions to u_{tot} . A large peak in the p-polarization term is still found near ω_L , but a new smaller peak is also present just above ω_T . However, the peak in the s-polarization contribution to u_{tot} previously found at ω_T is now a minimum, with a larger peak below this frequency and a smaller peak above that coincides with the position of the lower peak in the p-polarization contribution. This leads to an overall three-peak structure in u_{tot} . This strongly contrasts with the results in Fig. 6, where the reflection coefficients for $c \parallel \hat{z}$ are nearly identical to the $\xi = 0$ results. Such a contrast was also present in our previous paper [15], where a difference in transverse and longitudinal nonlocal terms had little effect on r_p , but a significant effect on u_{tot} . The overall effect of the ABC choice remains the same as in previous sections.

From this and the previous sections, it is clear that if multiple spatially dispersive resonances are present in a medium, then they cannot be considered separately. Each of these results displays behavior not present in the single-resonance case, such as the suppression of peaks in $u_{\rm tot}$ associated with the p polarization in closely spaced parabolic bands, the difference between the heavy/light exciton model to the single-band approximations, and, finally, the additional $u_{\rm tot}$ peak from linear splitting in exciton bands.

VIII. CONCLUSIONS

We have extended the work of Halevi and Fuchs [43] to derive exact expressions for electromagnetic reflection and transmission coefficients at the boundary of a medium with multiple spatially dispersive resonances in the susceptibility. Surface effects are included by using phenomenological reflection coefficients U_{mi} for the polarization waves at the boundary. We have compared the results for several multiresonance media, using a variety of U_{mi} values corresponding to ABCs in the literature. In the case of heavy/light exciton bands, we have found an improved fit for the single-band approximation with $\sqrt{D^*} = (\sqrt{D_h} + \sqrt{D_l})/2$.

The model has been extended to alternate exciton dispersion relations with the inclusion of a linear splitting term in $\omega(k)$ typical of uniaxial crystals. We have compared the results when the crystal axis c is aligned with each of the coordinate axes in our system The largest effects were seen with c perpendicular to the plane of incidence for s polarization and in the plane of incidence, parallel to the surface, for p polarization.

Finally, we have used the calculated reflection coefficients to find the zero-point and thermal spectral energy density $u_{\text{tot}}(z,\omega)$ outside the dielectric. Many features are the same as the single-resonance model, such as the effect of the ABC choice and the saturation of u_{tot} as $z \to 0$. However, there is different behavior that is only present when the multiple resonances are considered together. We have found that close resonances can lead to significant suppression in the peaks of $u_{\text{tot}}(\omega)$ and that single-band approximations fail to capture the correct behavior of the heavy/light exciton band model. The linear splitting term led to significant changes for u_{tot} in the uniaxial crystal by splitting the peak at the resonant frequency to give an overall three-peak structure.

While the model presented here incorporates many more of the features found in real materials than the model of Halevi and Fuchs, it could be extended further to include differences between the transverse and longitudinal susceptibilities [15] or higher-order nonlocal terms. This could also be applied to other problems, such as identifying which ABC is most appropriate for a medium with a complex exciton band structure, or in the calculation of Casimir self-forces [10].

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